



30V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C		
-30V	$6.8 \text{m}\Omega$ @ $V_{GS} = -10V$	-50A		
	$13m\Omega$ @ $V_{GS} = -4.5V$	-36A		

Description and Applications

This MOSFET has been designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Low R_{DS(ON)} Ensures On State Losses are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- 100% Unclamped Inductive Switching (Test in Production)
 Ensures More Reliability
- HBM ESD Protection Level of 8kV Typical
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

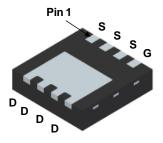
Mechanical Data

- Case: V-DFN3333-8 (Type B)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Below Diagram Terminals: Finish –NiPdAu over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208
- Weight: 0.030 grams (Approximate)

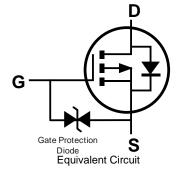








Bottom View



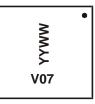
Ordering Information (Note 5)

Part Number	Case	Packaging
DMP3007SCGQ-7	V-DFN3333-8 (Type B)	2,000/Tape & Reel
DMP3007SCGQ-13	V-DFN3333-8 (Type B)	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



V07= Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-30	V
Gate-Source Voltage			V _{GSS}	±25	V
Continuous Drain Current (Note 8) $V_{GS} = -10V$ Steady $T_C = +25^{\circ}C$ State $T_C = +70^{\circ}C$			I _D	-50 -40	А
Maximum Continuous Body Diode Forward Current (Note 8)			Is	-40	Α
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)			I _{DM}	-100	Α
Avalanche Current (Note 9) L = 1mH			I _{AS}	-16	Α
Avalanche Energy (Note 9) L = 1mH			E _{AS}	130	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	$T_A = +25$ °C	P _D	1.0	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	124	°C/W
Total Power Dissipation (Note 7)	T _A = +25°C	P _D	2.4	W
Thermal Resistance, Junction to Ambient (Note 7) Steady State		$R_{\theta JA}$	52	°C/W
Thermal Resistance, Junction to Case (Note 8)	R ₀ JC	4.0	°C/W	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 10)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-1	μΑ	V _{DS} = -24V, V _{GS} = 0V	
Gate-Source Leakage		-	_	±10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 10)							
Gate Threshold Voltage	V _{GS(TH)}	-1.0		-3.0	٧	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
Static Drain-Source On-Resistance		-	5.7	6.8	mΩ	$V_{GS} = -10V, I_D = -11.5A$	
Static Dialii-Source Oil-Resistance	R _{DS(ON)}	_	8.0	13		$V_{GS} = -4.5V, I_D = -8.5A$	
Diode Forward Voltage	V _{SD}	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 11)							
Input Capacitance	C _{iss}		2,826	_	pF	V _{DS} = -15V, V _{GS} = 0V, -f = 1.0MHz	
Output Capacitance	Coss	_	606	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	305	_	pF		
Gate Resistance	Rg	_	23	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Qg	-	31.2	_	nC		
Total Gate Charge (V _{GS} = -10V)	Qg	-	64.2	_	nC	15// 45/	
Gate-Source Charge	Q _{gs}	-	10.6	_	nC	$V_{DS} = -15V, I_{D} = -11.5A$	
Gate-Drain Charge	Q _{gd}	-	11.6	_	nC		
Turn-On Delay Time	t _{D(ON)}	-	4.8	_	ns		
Turn-On Rise Time	t _R		4.3	_	ns	$V_{DD} = -15V$, $V_{GS} = -10V$, $R_g = 6\Omega$, $I_D = -11.5A$	
Turn-Off Delay Time	t _{D(OFF)}		306	_	ns		
Turn-Off Fall Time	t _F		125	_	ns		
Reverse Recovery Time	t _{RR}	_	19	_	ns		
Reverse Recovery Charge	Q _{RR}	_	9.8	_	nC	$I_S = -11.5A$, dl/dt = 100A/ μ s	

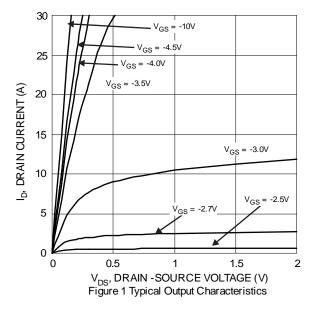
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:

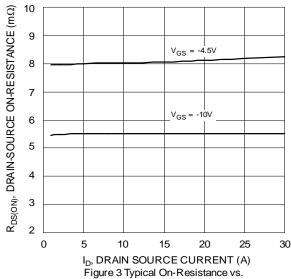
^{9.} I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25$ °C.

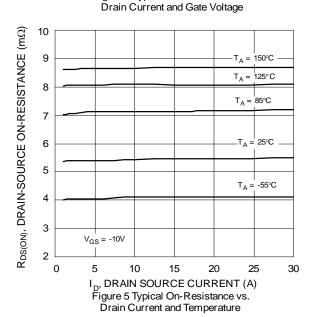
^{10.} Short duration pulse test used to minimize self-heating effect.

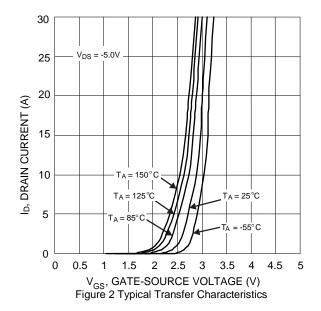
^{11.} Guaranteed by design. Not subject to product testing.

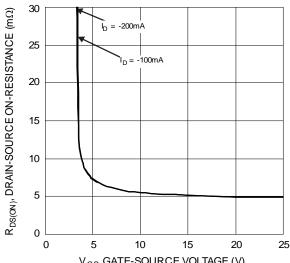




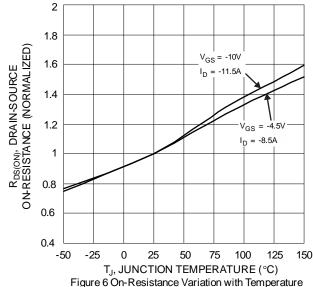








V_{GS} GATE-SOURCE VOLTAGE (V) Figure 4 Typical Drain-Source On-Resistance vs. Gate-Source Voltage



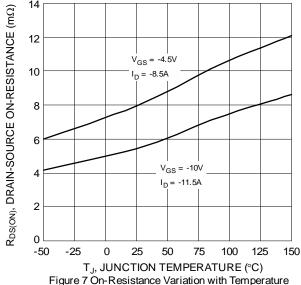
July 2018

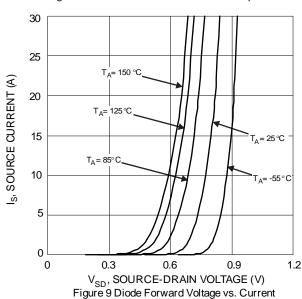
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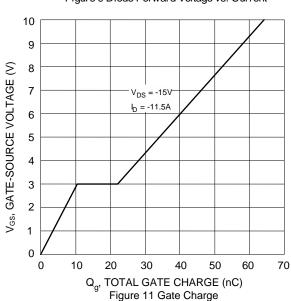
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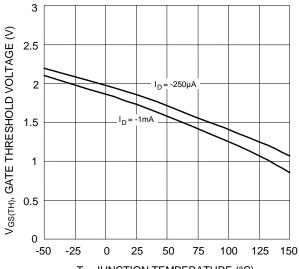
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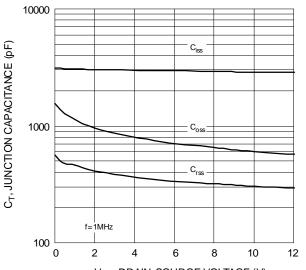




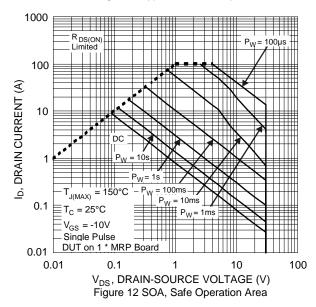




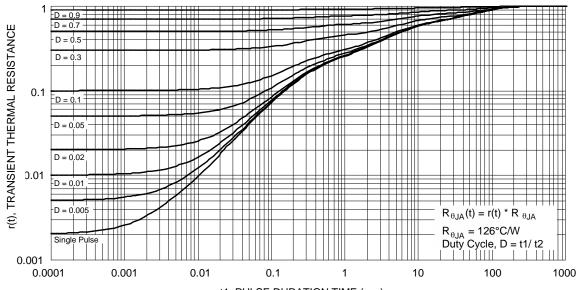
 $\label{eq:total_total} T_J, \, \text{JUNCTION TEMPERATURE (°C)}$ Figure 8 Gate Threshold Variation vs. Junction Temperature



V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 10 Typical Junction Capacitance







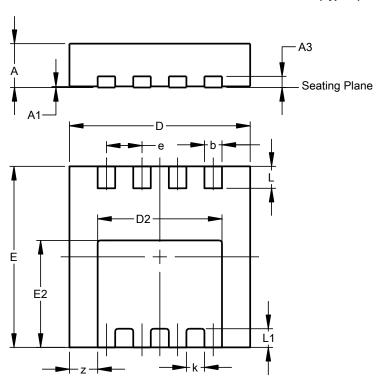
t1, PULSE DURATION TIME (sec) Figure 13 Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

V-DFN3333-8 (Type B)

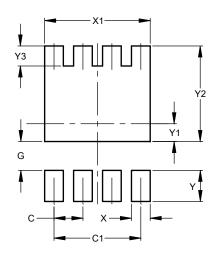


V-DFN3333-8					
(Type B)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	-	-	0.203		
b	0.27	0.37	0.32		
D	3.25	3.35	3.30		
D2	2.17	2.37	2.27		
Е	3.25	3.35	3.30		
E2	1.85	2.05	1.95		
е			0.65		
k	-		0.33		
L	0.35	0.45	0.40		
L1	-		0.34		
Z			0.515		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

V-DFN3333-8 (Type B)



Dimensions	Value (in mm)		
C	0.650		
C1	1.950		
G	0.650		
X	0.420		
X1	2.370		
Υ	0.700		
Y1	0.400		
Y2	2.150		
Y3	0.450		



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